NSN 5961-01-199-8950

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View Online at https://aerobasegroup.com/nsn/5961-01-199-8950 **Inclosure Material:** Plastic **Overall Length:** 15.3 millimeters **Overall Height:** 4.8 millimeters **Overall Width:** 11.5 millimeters **Mounting Facility Quantity: Internal Configuration:** Field effect Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-220 **Mounting Method:** Unthreaded hole **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: -140.0 drain to source voltage **Current Rating Per Characteristic:** -500.00 milliamperes drain current **Power Rating Per Characteristic:** 30.0 watts total power dissipation **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius ambient air **Terminal Type And Quantity:** 3 pin Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: